NSN 5961-01-149-1095

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View Online at https://aerobasegroup.com/nsn/5961-01-149-1095

Inclosure Material:
Metal
Overall Length:
0.850 inches
End Application:
Ticonderoga class cg (47); spruance class dd (963); forrestal class cv; nimitz class cvn; kidd class ddg; oliver perry class ffg; wasp clas
Ihd; tarawa class Iha; emory s land class as
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-61
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.687 inches
Thread Size:
0.250 inches
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 collector to emitter voltage/static/base open and 500.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage
dc
Current Rating Per Characteristic:
15.00 amperes source cutoff current blank and 10.00 amperes source cutoff current and 5.00 amperes source cutoff current
Power Rating Per Characteristic:
125 0 watta amall gignal input nowar, common callector absolute

125.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

7.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Weapon system essential; junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug and 1 threaded stud

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0